

#### Helping Customers Innovate, Improve & Grow

Table 1. Electrical Performance						
Parameter	Symbol	Min.	Тур	Max	Units	
Nominal Frequency	F <sub>NOM</sub>	8.000		60.000	MHz	
Mode	Fundamental or 3rd Overtone					
Operating Temperature Range	T <sub>OP</sub>	0/70, -	°C			
Stability Over T <sub>OP</sub> <sup>1</sup>	F <sub>STAB</sub>	±10		±100	ppm	
Frequency Tolerance <sup>2</sup>	F <sub>TOL</sub>		±10		ppm	
Load Capacitance	C <sub>L</sub>	6		32	pF	
Shunt Capacitance	C <sub>o</sub>			5	pF	
Drive Level			10	100	uW	
Aging / 1st year (at 25 °C)	$F_{AGE}$			±5	ppm	
Insulation Resistance		500			MOhm	
Storage Temperature	T <sub>sto</sub>	-40		90	°C	
		eries Resistance				
Crystal Frequency 8.000MHz-12.000MHz 12.001MHz-16.000MHz 16.001MHz-20.000MHz 20.001MHz-60.000MHz	ESR			100 80 70 50	Ohm	

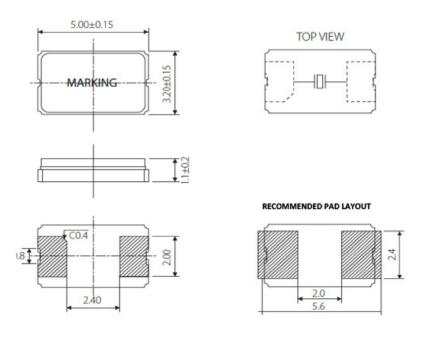
#### Notes:

- 1. Referenced to the Frequency at 25 °C.
- 2. Frequency measured at 25 °C  $\pm$  3 °C.

Product is compliant to RoHS directive and fully compatible with lead free assembly.

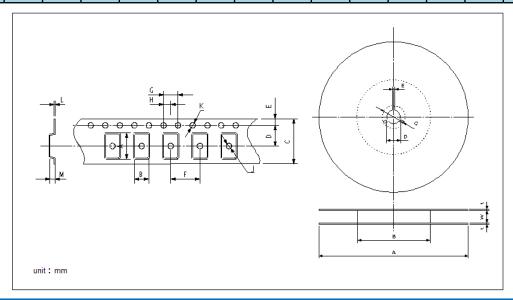


### **Package Drawing**



# Tape & Reel

Table	Table 7. Tape and Reel Dimensions (mm)																	
Tape												Reel						
Α	В	С	D	Ε	F	G	Н	J	K	L	М	Α	В	С	D	Е	W	Т
5.25	3.45	12.0	5.5	1.75	8.0	4.0	2.0	1.5	1.5	0.3	1.1	178	180	21.0	13.0	2.0	12.4	2.0



# Reliability & IR Compliance

### Solderprofile:

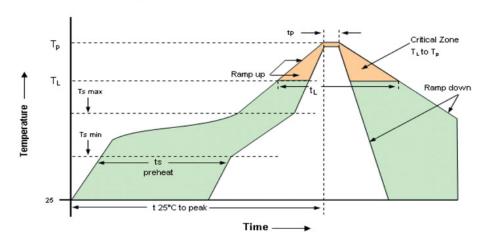
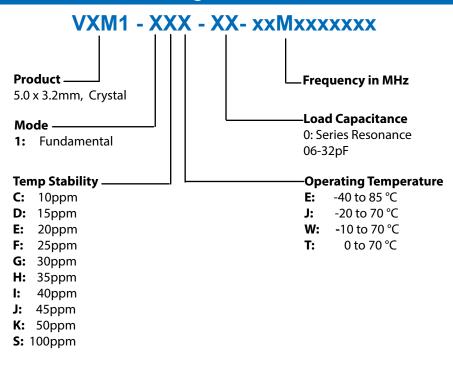


Table 2: Reflow Profile						
Parameter	Symbol	Value				
PreHeat Time Ts-min Ts-max	t <sub>s</sub>	60 sec Min, 260 sec Max 150°C 200°C				
Ramp Up	R <sub>UP</sub>	3 °C/sec Max				
Time Above 217 °C	t <sub>L</sub>	60 sec Min, 150 sec Max				
Time To Peak Temperature	T <sub>AMB-P</sub>	480 sec Max				
Time at 260 °C	t <sub>p</sub>	30 sec Max				
Ramp Down	R <sub>DN</sub>	6 °C/sec Max				

Pads are Au over Ni and compatible with either SnPb or Pb free attachment. MSL: 1

### **Ordering Information**



\*Note: not all combination of options are available. Other specifications may be available upon request.

10ppm stability not available for -40 to 85°C

\* Add **\_SNPBDIP** for tin lead solder dip Example: VXM1-1KE-18-10M0000000 SNPBDIP

### **Revision History**

Revision Date	Approved	Description						
August 29, 2016	RC	Initial datasheet for factory approval and release to customer.						
August 10, 2018	FB	Update logo and contact infromation, add "SNPBDIP" ordering option						



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